

MC78LC00 Series

Voltage Regulator - Micropower

The MC78LC00 series of fixed output low dropout linear regulators are designed for handheld communication equipment and portable battery powered applications which require low quiescent current. The MC78LC00 series features an ultra-low quiescent current of 1.1 μA . Each device contains a voltage reference unit, an error amplifier, a PMOS power transistor, and resistors for setting output voltage.

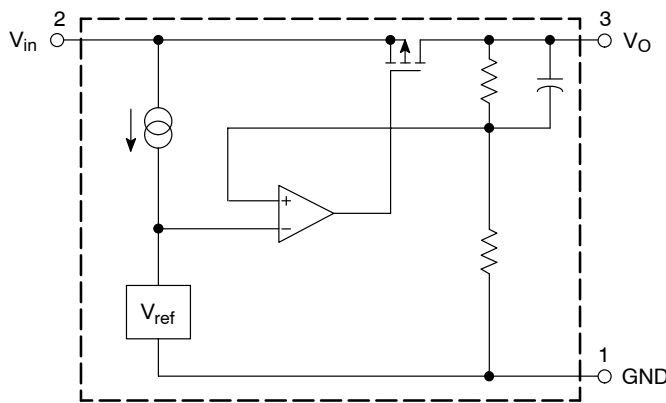
The MC78LC00 has been designed to be used with low cost ceramic capacitors and requires a minimum output capacitor of 0.1 μF . The device is housed in the micro-miniature Thin SOT23-5 surface mount package and SOT-89, 3 pin. Standard voltage versions are 1.5, 1.8, 2.5, 2.7, 2.8, 3.0, 3.3, 4.0, and 5.0 V. Other voltages are available in 100 mV steps.

Features

- Low Quiescent Current of 1.1 μA Typical
- Excellent Line and Load Regulation
- Maximum Operating Voltage of 12 V
- Low Output Voltage Option
- High Accuracy Output Voltage of 2.5%
- Industrial Temperature Range of -40°C to 85°C
- Two Surface Mount Packages (SOT-89, 3 Pin, or SOT-23, 5 Pin)
- These are Pb-Free Devices

Typical Applications

- Battery Powered Instruments
- Hand-Held Instruments
- Camcorders and Cameras



This device contains 8 active transistors.

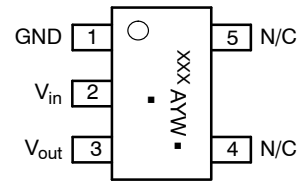
Figure 1. Representative Block Diagram



ON Semiconductor®

www.onsemi.com

MARKING DIAGRAMS AND PIN CONNECTIONS



(Top View)

XXX= Specific Device Code

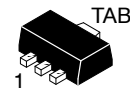
A = Assembly Location

Y = Year

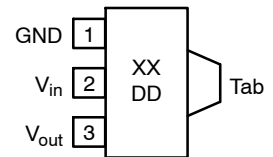
W = Work Week

▪ = Pb-Free Package

(Note: Microdot may be in either location)



SOT-89
H SUFFIX
CASE 1213



(Top View)

(Tab is connected to Pin 2)

XX = Specific Device Code

DD = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

MC78LC00 Series

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	GND	Power supply ground
2	V_{in}	Positive power supply input voltage
3	V_{out}	Regulated Output
4	N/C	No Internal Connection
5	N/C	No Internal Connection

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V_{in}	12	V
Output Voltage	V_{out}	-0.3 to $V_{in} + 0.3$	V
Power Dissipation and Thermal Characteristics Case 483-01 (Thin SOT23-5) NTR Suffix Power Dissipation @ $T_A = 85^\circ\text{C}$ Thermal Resistance, Junction-to-Ambient Case 1213 (SOT-89) H Suffix Power Dissipation @ $T_A = 25^\circ\text{C}$ Thermal Resistance, Junction-to-Ambient	P_D $R_{\theta JA}$ P_D $R_{\theta JA}$	140 280 900 111	mW $^\circ\text{C}/\text{W}$ mW $^\circ\text{C}/\text{W}$
Operating Junction Temperature	T_J	+125	$^\circ\text{C}$
Operating Ambient Temperature	T_A	-40 to +85	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Lead Soldering Temperature @ 260 $^\circ\text{C}$	T_{solder}	10	sec

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

MC78LC00 Series

ELECTRICAL CHARACTERISTICS ($V_{in} = V_{out(nom.)} + 1.0\text{ V}$, $C_{in} = 1.0\ \mu\text{F}$, $C_{out} = 1.0\ \mu\text{F}$, $T_J = 25^\circ\text{C}$, unless otherwise noted.) (Note 5)

NTR SUFFIX

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($T_A = 25^\circ\text{C}$, $I_{out} = 1.0\text{ mA}$)	V_{out}	1.455	1.5	1.545	V
1.5 V		1.746	1.8	1.854	
1.8 V		2.425	2.5	2.575	
2.5 V		2.646	2.7	2.754	
2.7 V		2.744	2.8	2.856	
2.8 V		2.94	3.0	3.06	
3.0 V		3.234	3.3	3.366	
3.3 V		3.9	4.0	4.1	
4.0 V		4.90	5.0	5.10	
5.0 V					
Output Voltage ($T_A = -40^\circ\text{C}$ to 85°C)	V_{out}	1.455	1.5	1.545	V
1.5 V		1.746	1.8	1.854	
1.8 V		2.425	2.5	2.575	
2.5 V		2.619	2.7	2.781	
2.7 V		2.716	2.8	2.884	
2.8 V		2.910	3.0	3.09	
3.0 V		3.201	3.3	3.399	
3.3 V		3.9	4.0	4.1	
4.0 V		4.90	5.0	5.10	
5.0 V					
Line Regulation ($V_{in} = V_{O(nom.)} + 1.0\text{ V}$ to 12 V , $I_{out} = 1.0\text{ mA}$)	Reg_{line}	–	0.05	0.2	%/V
Load Regulation ($I_{out} = 1.0\text{ mA}$ to 10 mA)	Reg_{load}	–	40	60	mV
Output Current (Note 6)	I_{out}				mA
1.5 V, 1.8 V ($V_{in} = 4.0\text{ V}$)		35	50	–	
2.5 V, 2.7 V, 2.8 V, 3.0 V ($V_{in} = 5.0\text{ V}$)		50	80	–	
3.3 V ($V_{in} = 6.0\text{ V}$)		50	80	–	
4.0 V ($V_{in} = 7.0\text{ V}$)		80	80	–	
5.0 V ($V_{in} = 8.0\text{ V}$)		80	100	–	
Dropout Voltage ($I_{out} = 1.0\text{ mA}$, Measured at $V_{out} - 3.0\%$)	$V_{in} - V_{out}$				mV
1.5 V		–	35	70	
1.6 V–3.2 V		–	30	60	
3.3 V–3.9 V		–	30	53	
4.0 V–5.0 V		–	30	38	
Quiescent Current ($I_{out} = 1.0\text{ mA}$ to $I_{O(nom.)}$)	I_Q	–	1.1	3.6	μA
Output Voltage Temperature Coefficient	T_c	–	± 100	–	ppm/ $^\circ\text{C}$
Output Noise Voltage ($f = 1.0\text{ kHz}$ to 100 kHz)	V_n	–	89	–	μVrms

- This device series contains ESD protection and exceeds the following tests:
Human Body Model 2000 V per MIL–STD–883, Method 3015
Machine Model Method 200 V
- Latch up capability (85°C) $\pm 100\text{ mA}$
- Maximum package power dissipation limits must be observed.

$$PD = \frac{T_J(\text{max}) - T_A}{R_{\theta JA}}$$

- Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
- Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
- Output Current is measured when $V_{out} = V_{O1} - 3\%$ where $V_{O1} = V_{out}$ at $I_{out} = 0\text{ mA}$.

MC78LC00 Series

ELECTRICAL CHARACTERISTICS ($V_{in} = V_{out(nom.)} + 1.0\text{ V}$, $C_{in} = 1.0\ \mu\text{F}$, $C_{out} = 1.0\ \mu\text{F}$, $T_J = 25^\circ\text{C}$, unless otherwise noted.) (Note 11)

HT SUFFIX

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage 30HT1 Suffix ($V_{in} = 5.0\text{ V}$) 33HT1 Suffix ($V_{in} = 5.0\text{ V}$) 40HT1 Suffix ($V_{in} = 6.0\text{ V}$) 50HT1 Suffix ($V_{in} = 7.0\text{ V}$)		2.950 3.218 3.900 4.875	3.0 3.3 4.0 5.0	3.075 3.382 4.100 5.125	V
Line Regulation $V_{in} = [V_O + 1.0]\text{ V}$ to 10 V, $I_O = 1.0\text{ mA}$	Reg_{line}	-	0.05	0.2	%/V
Load Regulation ($I_O = 1.0$ to 10 mA) 30HT1 Suffix ($V_{in} = 5.0\text{ V}$) 33HT1 Suffix ($V_{in} = 6.0\text{ V}$) 40HT1 Suffix ($V_{in} = 7.0\text{ V}$) 50HT1 Suffix ($V_{in} = 8.0\text{ V}$)	Reg_{load}	- - - -	40 40 50 60	60 60 70 90	mV
Output Current (Note 12) 30HT1 Suffix ($V_{in} = 5.0\text{ V}$) 33HT1 Suffix ($V_{in} = 6.0\text{ V}$) 40HT1 Suffix ($V_{in} = 7.0\text{ V}$) 50HT1 Suffix ($V_{in} = 8.0\text{ V}$)	I_O	35 35 45 55	50 50 65 80	- - - -	mA
Dropout Voltage 30HT1 Suffix ($I_O = 1.0\text{ mA}$) 33HT1 Suffix ($I_O = 1.0\text{ mA}$) 40HT1 Suffix ($I_O = 1.0\text{ mA}$) 50HT1 Suffix ($I_O = 1.0\text{ mA}$)	$V_{in} - V_O$	- - - -	40 35 25 25	60 53 38 38	mV
Quiescent Current 30HT1 Suffix ($V_{in} = 5.0\text{ V}$) 33HT1 Suffix ($V_{in} = 5.0\text{ V}$) 40HT1 Suffix ($V_{in} = 6.0\text{ V}$) 50HT1 Suffix ($V_{in} = 7.0\text{ V}$)	I_{CC}	- - - -	1.1 1.1 1.2 1.3	3.3 3.3 3.6 3.9	μA
Output Voltage Temperature Coefficient	T_C	-	± 100	-	ppm/ $^\circ\text{C}$

7. This device series contains ESD protection and exceeds the following tests:

Human Body Model 2000 V per MIL-STD-883, Method 3015
Machine Model Method 200 V

8. Latch up capability (85°C) $\pm 100\text{ mA}$

9. Maximum package power dissipation limits must be observed.

$$PD = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

10. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

11. Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible.

12. Output Current is measured when $V_{out} = V_{O1} - 3\%$ where $V_{O1} = V_{out}$ at $I_{out} = 0\text{ mA}$.

DEFINITIONS

Load Regulation

The change in output voltage for a change in output current at a constant temperature.

Dropout Voltage

The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 3% below its nominal. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

Maximum Power Dissipation

The maximum total dissipation for which the regulator will operate within its specifications.

Quiescent Current

The quiescent current is the current which flows through the ground when the LDO operates without a load on its output: internal IC operation, bias, etc. When the LDO becomes loaded, this term is called the Ground current. It is actually the

difference between the input current (measured through the LDO input pin) and the output current.

Line Regulation

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse technique such that the average chip temperature is not significantly affected.

Line Transient Response

Typical over and undershoot response when input voltage is excited with a given slope.

Maximum Package Power Dissipation

The maximum power package dissipation is the power dissipation level at which the junction temperature reaches its maximum operating value, i.e. 125°C . Depending on the ambient power dissipation and thus the maximum available output current.

MC78LC00 Series

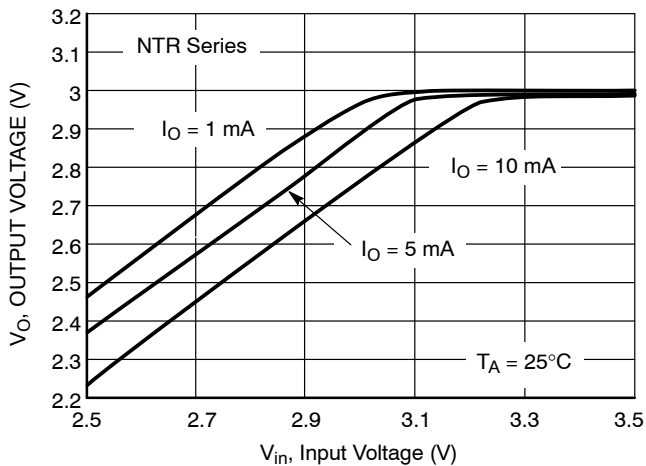


Figure 2. Output Voltage versus Input Voltage

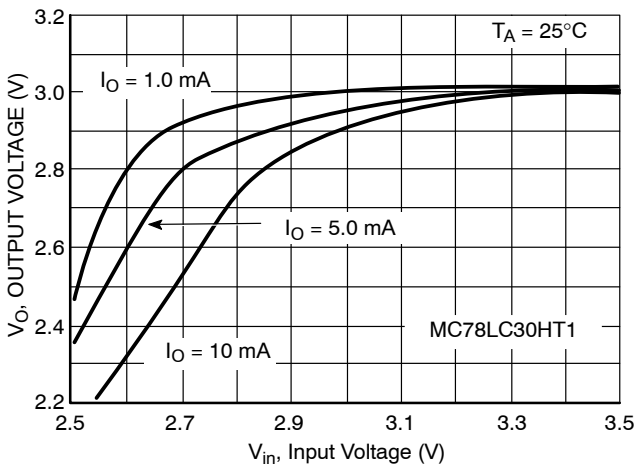


Figure 3. Output Voltage versus Input Voltage

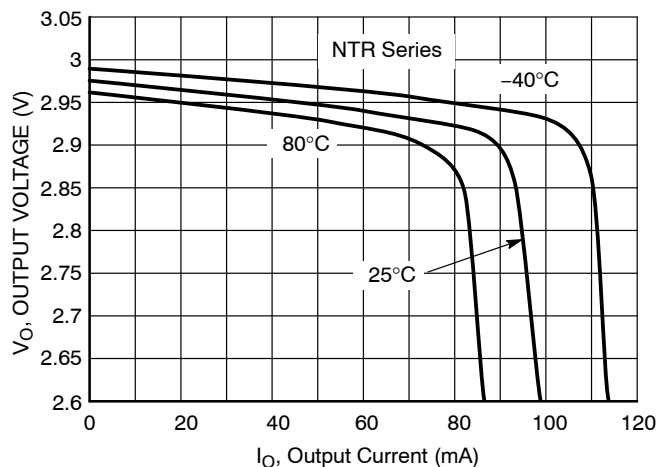


Figure 4. Output Voltage versus Output Current

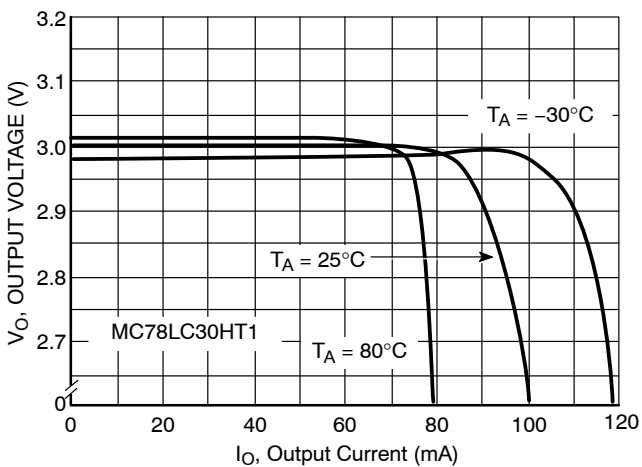


Figure 5. Output Voltage versus Output Current

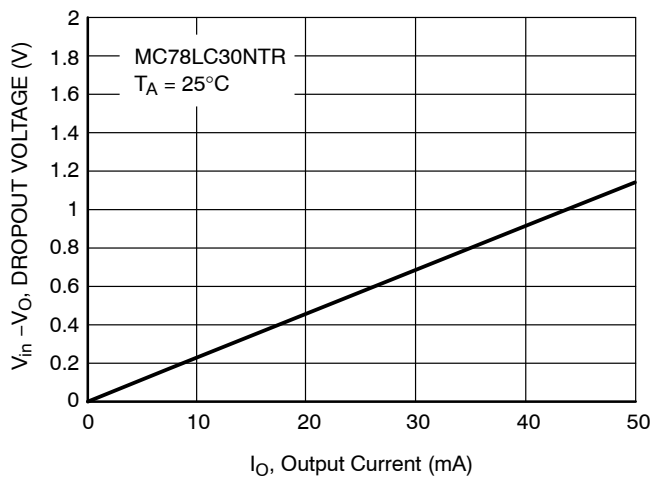


Figure 6. Dropout Voltage versus Output Current

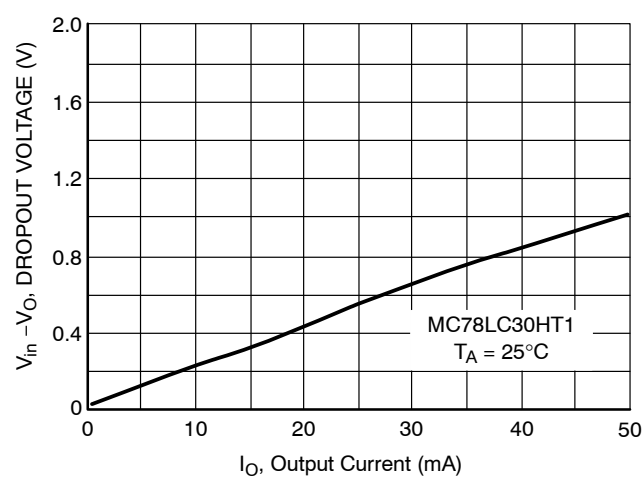


Figure 7. Dropout Voltage versus Output Current

MC78LC00 Series

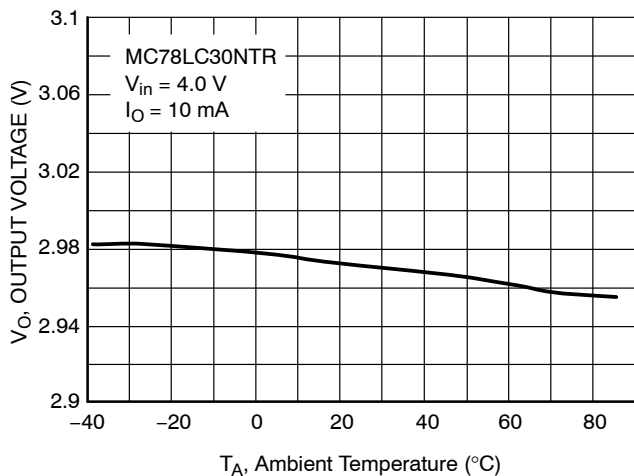


Figure 8. Output Voltage versus Temperature

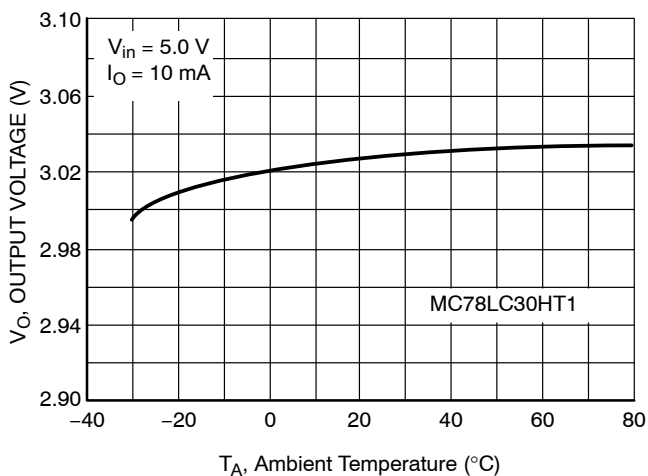


Figure 9. Output Voltage versus Temperature

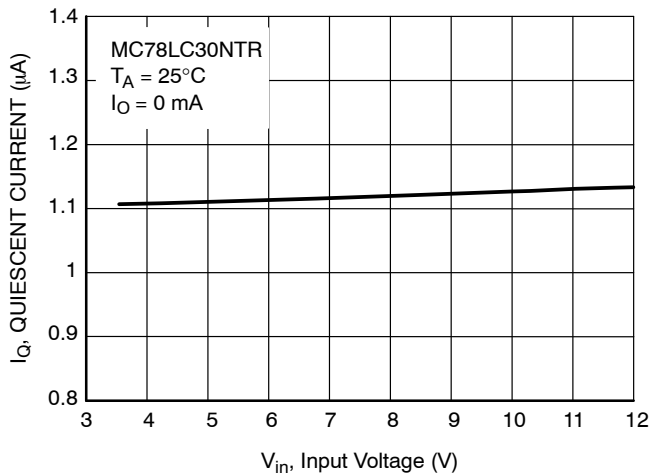


Figure 10. Quiescent Current versus Input Voltage

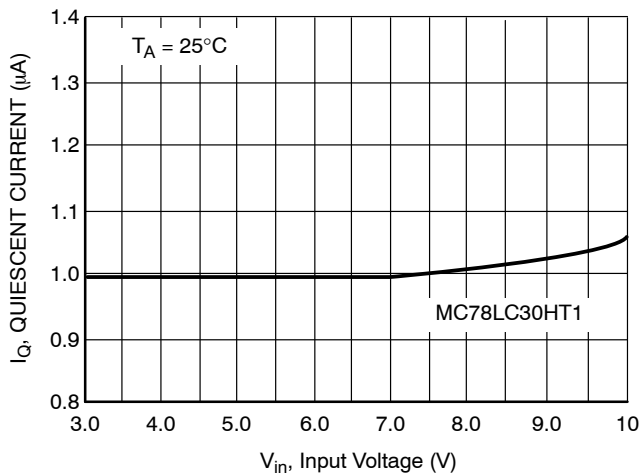


Figure 11. Quiescent Current versus Input Voltage

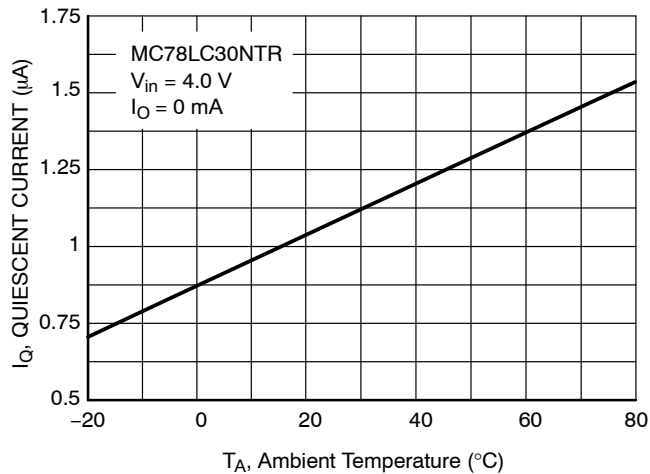


Figure 12. Quiescent Current versus Temperature

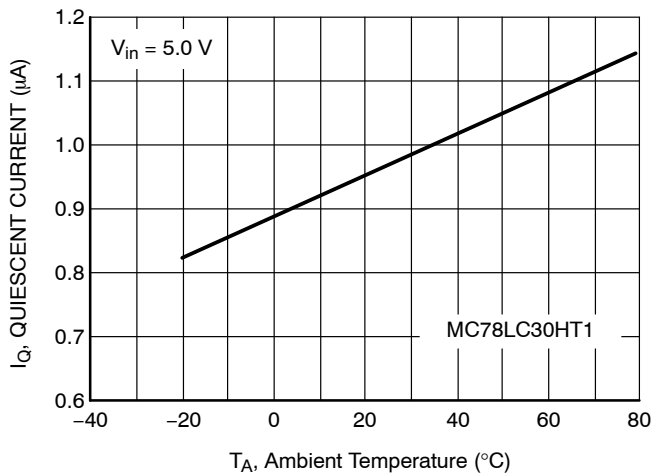


Figure 13. Quiescent Current versus Temperature

MC78LC00 Series

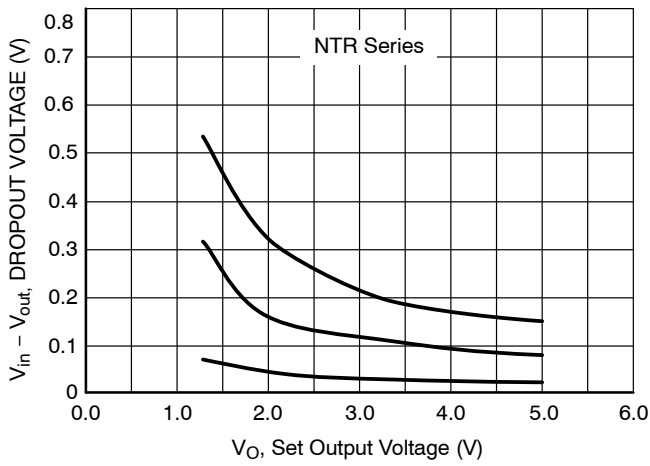


Figure 14. Dropout Voltage versus Set Output Voltage

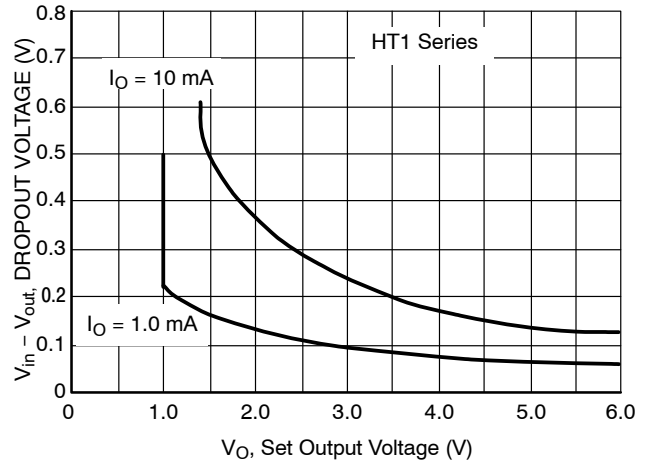


Figure 15. Dropout Voltage versus Set Output Voltage

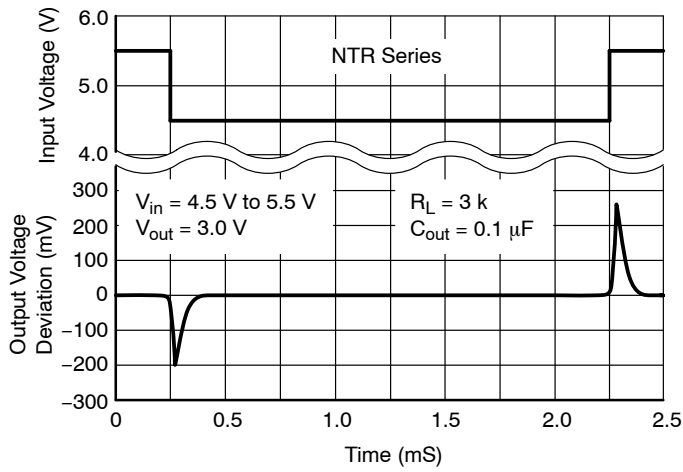


Figure 16. Line Transient

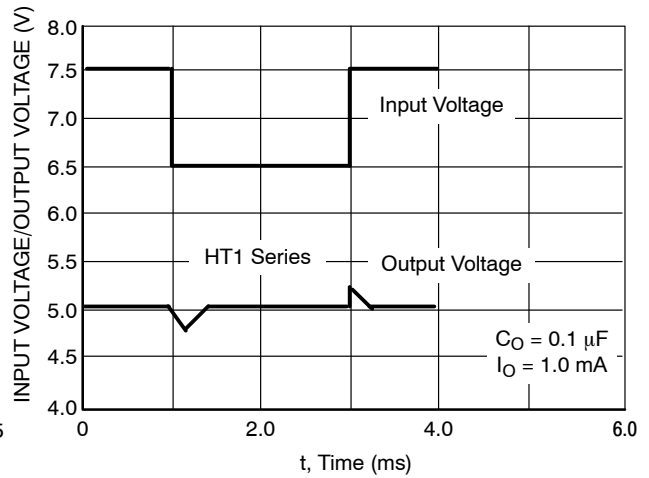


Figure 17. Line Transient Response

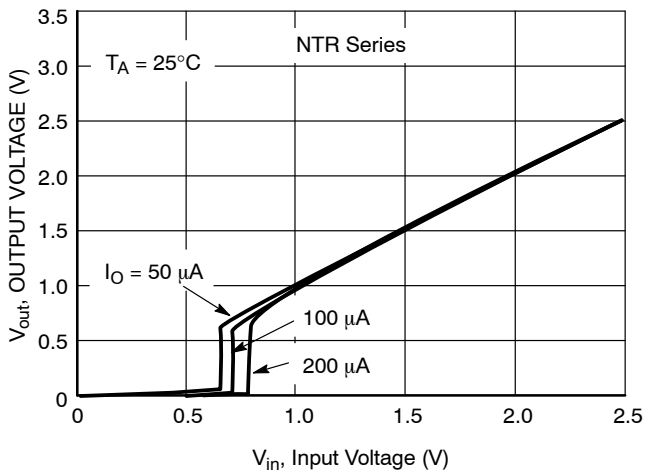


Figure 18. Output Voltage versus Input Voltage

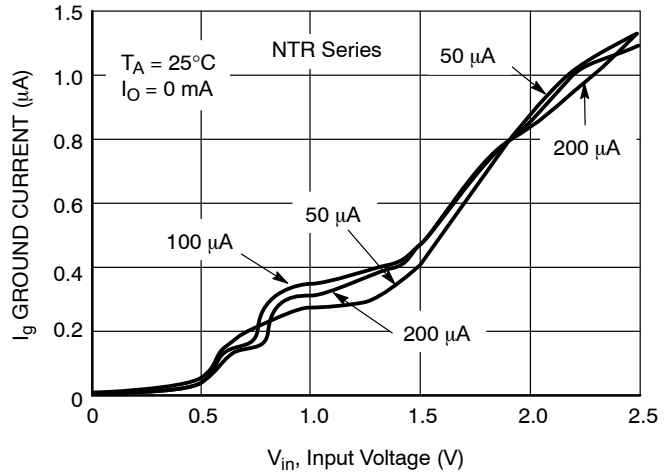


Figure 19. Ground Current versus Input Voltage

MC78LC00 Series

APPLICATIONS INFORMATION

A typical application circuit for the MC78LC00 series is shown in Figure 20.

Input Decoupling (C1)

A 0.1 μF capacitor either ceramic or tantalum is recommended and should be connected close to the MC78LC00 package. Higher values and lower ESR will improve the overall line transient response.

Output Decoupling (C2)

The MC78LC00 is a stable component and does not require any specific Equivalent Series Resistance (ESR) or a minimum output current. Capacitors exhibiting ESRs ranging from a few $\text{m}\Omega$ up to $3.0\ \Omega$ can thus safely be used. The minimum decoupling value is 0.1 μF and can be augmented to fulfill stringent load transient requirements. The regulator accepts ceramic chip capacitors as well as tantalum devices. Larger values improve noise rejection and load regulation transient response.

Hints

Please be sure the V_{in} and GND lines are sufficiently wide. When the impedance of these lines is high, there is a chance to pick up noise or cause the regulator to malfunction.

Set external components, especially the output capacitor, as close as possible to the circuit, and make leads as short as possible.

Thermal

As power across the MC78LC00 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and also the ambient temperature effect the rate of temperature rise for the part. This is stating that when the MC78LC00 has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power dissipation applications.

The maximum dissipation the package can handle is given by:

$$PD = \frac{T_{J(\text{max})} - T_A}{R_{\theta JA}}$$

If junction temperature is not allowed above the maximum 125°C , then the MC78LC00NTR can dissipate up to $357\ \text{mW}$ @ 25°C .

The power dissipated by the MC78LC00NTR can be calculated from the following equation:

$$P_{\text{tot}} = [V_{\text{in}} * I_{\text{gnd}} (I_{\text{out}})] + [V_{\text{in}} - V_{\text{out}}] * I_{\text{out}}$$

or

$$V_{\text{inMAX}} = \frac{P_{\text{tot}} + V_{\text{out}} * I_{\text{out}}}{I_{\text{gnd}} + I_{\text{out}}}$$

If an 80 mA output current is needed then the ground current from the data sheet is $1.1\ \mu\text{A}$. For an MC78LC30NTR (3.0 V), the maximum input voltage will then be 7.4 V.

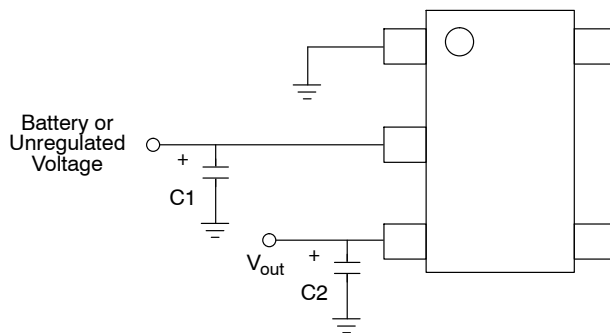


Figure 20. Basic Application Circuit for NTR Suffixes

MC78LC00 Series

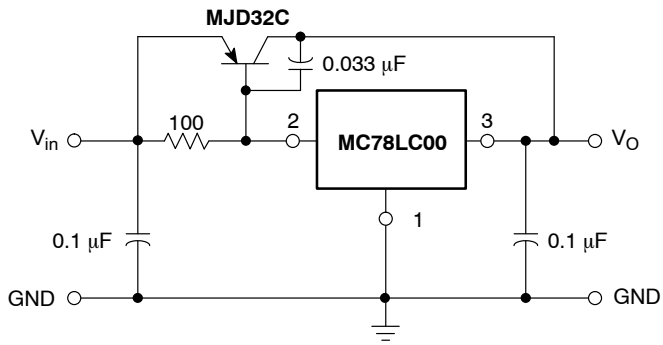


Figure 21. Current Boost Circuit

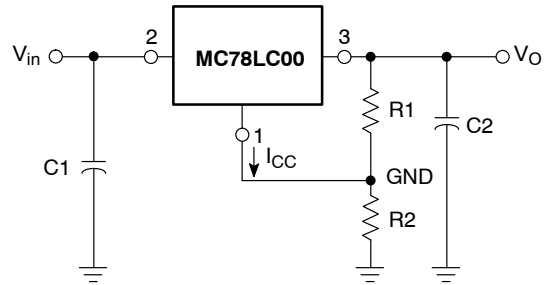


Figure 22. Adjustable V_O

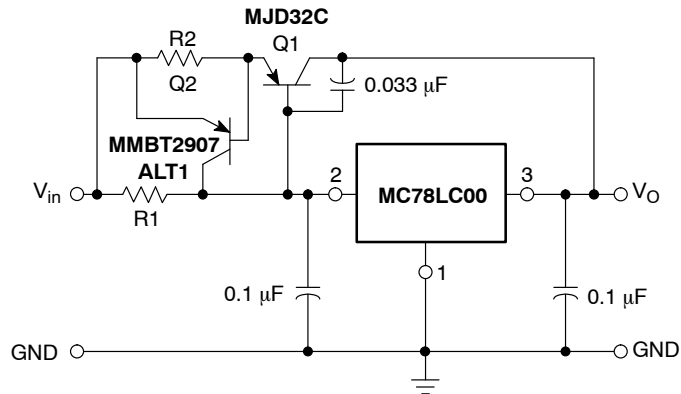


Figure 23. Current Boost Circuit with Overcurrent Limit Circuit

$$V_O = V_{O(\text{Reg})} \left(1 + \frac{R_2}{R_1} \right) + I_{CC} R_2$$

$$I_{O(\text{short circuit})} \approx \frac{V_{BE2}}{R_2} + \frac{V_{BE1} + V_{BE2}}{R_1}$$

MC78LC00 Series

ORDERING INFORMATION

Device	Nominal Output Voltage	Marking	Package	Shipping [†]
MC78LC15NTRG	1.5	LAG	Thin SOT23-5 (Pb-Free)	3000 Units/7" Tape & Reel
MC78LC18NTRG	1.8	LAH		
MC78LC25NTRG	2.5	LAI		
MC78LC27NTRG	2.7	LAJ		
MC78LC28NTRG	2.8	LAK		
MC78LC30NTRG	3.0	LAL		
MC78LC33NTRG	3.3	LAM		
MC78LC40NTRG	4.0	LEC		
MC78LC50NTRG	5.0	LAN		
MC78LC30HT1G	3.0	0C		
MC78LC33HT1G	3.3	3C		
MC78LC40HT1G	4.0	0D		
MC78LC50HT1G	5.0	0E		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
Additional voltages in 100 mV steps are available upon request by contacting your ON Semiconductor representative.

MECHANICAL CASE OUTLINE

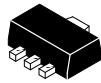
PACKAGE DIMENSIONS

ON Semiconductor®

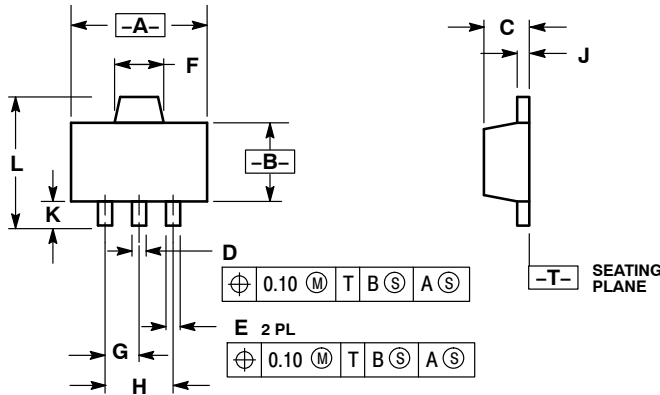


SOT-89 (3-LEAD) CASE 1213-02 ISSUE C

DATE 05/24/2001



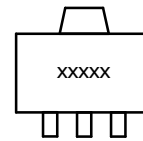
SCALE 2:1



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS
 3. 1213-01 OBSOLETE, NEW STANDARD 1213-02.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.40	4.60	0.173	0.181
B	2.40	2.60	0.094	0.102
C	1.40	1.60	0.055	0.063
D	0.37	0.57	0.015	0.022
E	0.32	0.52	0.013	0.020
F	1.50	1.83	0.059	0.072
G	1.50 BSC		0.059 BSC	
H	3.00 BSC		0.118 BSC	
J	0.30	0.50	0.012	0.020
K	0.80	---	0.031	---
L	---	4.25	---	0.167

MARKING DIAGRAM



xxxxxx = Specific Device Code

STYLE 1:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

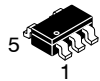
STYLE 2:
PIN 1. BASE
2. COLLECTOR
3. EMITTER

DOCUMENT NUMBER:	98ASH70519A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOT-89 (3-LEAD)	PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

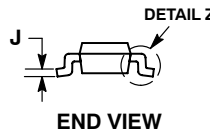
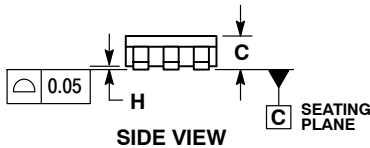
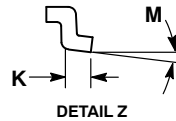
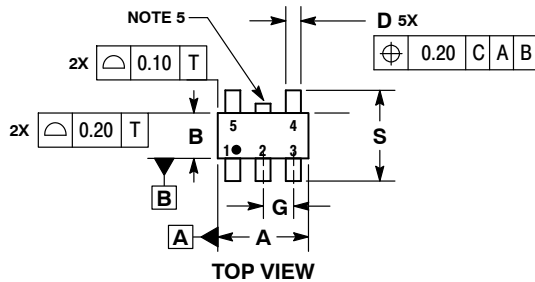
ON Semiconductor®



SCALE 2:1

TSOP-5 CASE 483 ISSUE N

DATE 12 AUG 2020

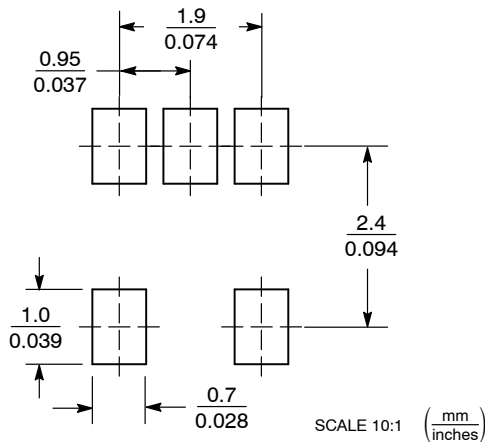


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

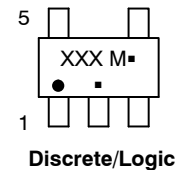
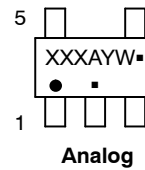
DIM	MILLIMETERS	
	MIN	MAX
A	2.85	3.15
B	1.35	1.65
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
M	0°	10°
S	2.50	3.00

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



- XXX = Specific Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- = Pb-Free Package
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

DOCUMENT NUMBER:	98ARB18753C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSOP-5	PAGE 1 OF 1

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:
Voice Mail: 1 800-282-9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative